

# Parastou Fakhimi

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/6705125/publications.pdf>

Version: 2024-02-01

2  
papers

93  
citations

2682572

2  
h-index

2917675

2  
g-index

2  
all docs

2  
docs citations

2  
times ranked

88  
citing authors

#	ARTICLE	IF	CITATIONS
1	431 kA/cm <sup>2</sup> peak tunneling current density in GaN/AlN resonant tunneling diodes. Applied Physics Letters, 2018, 112, .	3.3	41
2	Highly repeatable room temperature negative differential resistance in AlN/GaN resonant tunneling diodes grown by molecular beam epitaxy. Applied Physics Letters, 2016, 109, .	3.3	52